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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.	
10/735,229	12/11/2003	Charles Frank Machala III	TI-36674	1860	
23494 75	23494 7590 08/10/2005			EXAMINER	
TEXAS INSTRUMENTS INCORPORATED P O BOX 655474, M/S 3999 DALLAS, TX 75265			GOUDREAU, GEORGE A		
			ART UNIT	PAPER NUMBER	
			1763	TALERIOMBER	

Please find below and/or attached an Office communication concerning this application or proceeding.

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	Application No.	Applicant(s)				
Office Astion Commence	10/735,229	MACHALA, CHARLES FRANK				
Office Action Summary	Examiner	Art Unit				
	George A. Goudreau	1763				
The MAILING DATE of this communication ap Period for Reply	pears on the cover sheet with the c	correspondence address				
A SHORTENED STATUTORY PERIOD FOR REPI THE MAILING DATE OF THIS COMMUNICATION. - Extensions of time may be available under the provisions of 37 CFR 1 after SIX (6) MONTHS from the mailing date of this communication. - If the period for reply specified above is less than thirty (30) days, a report of 18 NO period for reply is specified above, the maximum statutory period for reply within the set or extended period for reply will, by statuted and the set of the set of the maximum statutory period for reply will, by statuted and the set of the set of the set of the maximum statutory period for reply will, by statuted and the set of	136(a). In no event, however, may a reply be tired by within the statutory minimum of thirty (30) day within the statutory minimum of thirty (30) day will apply and will expire SIX (6) MONTHS from the cause the application to become ABANDONE	nely filed s will be considered timely. the mailing date of this communication. D (35 U.S.C. § 133).				
Status						
1) Responsive to communication(s) filed on 02 I	May 2005.					
_ ` <u> </u>	s action is non-final.					
3)☐ Since this application is in condition for allowa		osecution as to the merits is				
closed in accordance with the practice under	· ·					
Disposition of Claims	,					
4) Claim(s) 1-19 is/are pending in the application	n					
4)⊠ Claim(s) <u>1-19</u> is/are pending in the application. 4a) Of the above claim(s) is/are withdrawn from consideration.						
5) Claim(s) is/are allowed.	awii iioiii consideration.					
6)⊠ Claim(s) <u>1-19</u> is/are rejected.						
7) Claim(s) is/are objected to.						
8) Claim(s) are subject to restriction and/	or election requirement					
o) Claim(o) are subject to restriction and	or election requirement.	•				
Application Papers		·				
9)☐ The specification is objected to by the Examin						
10)☐ The drawing(s) filed on is/are: a)☐ ac	cepted or b) \square objected to by the \square	Examiner.				
Applicant may not request that any objection to the	drawing(s) be held in abeyance. See	e 37 CFR 1.85(a).				
Replacement drawing sheet(s) including the correct	ction is required if the drawing(s) is ob	jected to. See 37 CFR 1.121(d).				
11)☐ The oath or declaration is objected to by the E	xaminer. Note the attached Office	Action or form PTO-152.				
Priority under 35 U.S.C. § 119						
12) Acknowledgment is made of a claim for foreign	n priority under 35 U.S.C. § 119(a))-(d) or (f).				
a) ☐ All b) ☐ Some * c) ☐ None of:						
1. Certified copies of the priority documen						
2. Certified copies of the priority documents have been received in Application No						
3. Copies of the certified copies of the priority documents have been received in this National Stage						
application from the International Burea	au (PCT Rule 17.2(a)).					
* See the attached detailed Office action for a lis	t of the certified copies not receive	ed Carana A O a O				
		GEORGE GOUDREAU PRIMARY EXAMINER				
Attachment(s)		8-051				
1) Notice of References Cited (PTO-892)	4) Interview Summary					
2) Notice of Draftsperson's Patent Drawing Review (PTO-948)	Paper No(s)/Mail Do	ate atent Application (PTO-152)				
Information Disclosure Statement(s) (PTO-1449 or PTO/SB/08 Paper No(s)/Mail Date	6) Other:	atom Application (FTO-102)				
J.S. Patent and Trademark Office						
PTOL-326 (Rev. 1-04) Office A	ction Summary	Part of Paper No./Mail Date 080805				



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1. This action will not be made final due to the new grounds of rejection.

2. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

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- 3. This application currently names joint inventors. In considering patentability of the claims under 35 U.S.C. 103(a), the examiner presumes that the subject matter of the various claims was commonly owned at the time any inventions covered therein were made absent any evidence to the contrary. Applicant is advised of the obligation under 37 CFR 1.56 to point out the inventor and invention dates of each claim that was not commonly owned at the time a later invention was made in order for the examiner to consider the applicability of 35 U.S.C. 103(c) and potential 35 U.S.C. 102(e), (f) or (g) prior art under 35 U.S.C. 103(a).
- 4. Claims 1-19 are rejected under 35 U.S.C. 103(a) as being unpatentable over Gardner et. al. (5,863,824) further in view of Nandakumar et. al. (6,150,669). Gardner et. al. disclose a process for fabricating a transistor comprised of the following steps:
 - -A gate dielectric layer (205) is formed onto the surface of a wafer (201).;
 - -A gate electrode (203) is formed onto the surface of the gate dielectric layer.;
 - -The gate dielectric layer, and the gate electrode are anisotropically etched.;
 - -The length of the gate electrode is measured using a SEM in the direction parallel to the channel and compared to targeted desired channel length.;

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and

-A SiO2 layer (207) may optionally be deposited onto the surface of the wafer.;

-A spacer dielectric layer (209), which is comprised of Si3N4, is then conformably deposited onto the surface of the wafer. The thickness of the Si3N4 layer, which is deposited onto the surface of the wafer, is determined based upon ½ the difference between the measured gate length, and the targeted channel length.;

-The spacer dielectric layer is then anisotropically etched to form the spacers on the sidewalls of the gate electrode.

This is discussed specifically in columns 2-5; and discussed in general in columns 1-6. This is shown in figures 1-3. Gardner et. al. fail, however, to specifically disclose the following aspects of applicant's claimed invention:

-the specific formation of the test structure in the scribe region of the wafer

Nandakumar et. al. teach that it is desirable to form test structures in the scribe

line region of a wafer, which are used for the measurement of the gate line width. This

is discussed specifically in the abstract; and discussed in general in columns 1-6. This

is shown in figures 1-8.

It would have been desirable to form test structures in the scribe line region of the wafer in the process taught by Gardner et. al. as applied above based upon the following. Nandakumar et. al. teach that it is desirable to form test structures used in the measurement of gate line widths in the scribe line region of a wafer.

5. Applicant's arguments with respect to claims of record have been considered but are most in view of the new ground(s) of rejection.

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6. The prior art made of record and not relied upon is considered pertinent to applicant's disclosure.

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7. Any inquiry concerning this communication should be directed to examiner George A. Goudreau at telephone number (571)-272-1434.

George A. Coudreáu
Primary Examiner

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